CARBIDE



Unibody-Design Femtosecond Lasers for Industry and Science

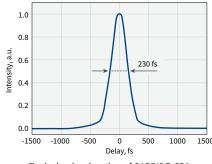
FEATURES

- Tunable pulse duration, 190 fs 20 ps
- Maximum output of 120 W, 1 mJ or 80 W, 2 mJ
- Single-shot 2 MHz repetition rate
- Pulse-on-demand and BiBurst for pulse control
- Up to 5th harmonic or tunable extensions
- Air-cooled model
- Compact industrial-grade design

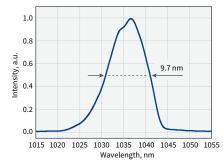


CARBIDE is a series of femtosecond lasers combining high average power and excellent power stability. CARBIDE features market-leading output parameters without compromises to beam quality and stability. A compact and robust optomechanical CARBIDE design allows a variety of applications in top-class research centers, as well as display, automotive, LED, medical, and other industries. The reliability of CARBIDE has been proven by hundreds of systems operating 24/7 in the industrial environment.

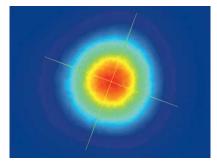
CARBIDE features high-power water-cooled (CB3) and air-cooled (CB5) models. The tunability of CARBIDE lasers enables our customers to discover the most efficient manufacturing processes. Tunable parameters include pulse duration (190 fs – 20 ps), repetition rate (single-shot – 2 MHz), pulse energy (up to 2 mJ), and average power (up to 120 W). A pulse-on-demand mode is available using the built-in pulse picker. The CARBIDE lasers can be equipped with industrial-grade modules, including but not limited to harmonic generators and optical parametric amplifiers.



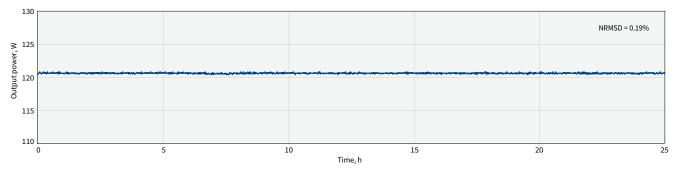
Typical pulse duration of CARBIDE-CB3



Typical spectrum of CARBIDE-CB3



Typical beam profile of CARBIDE-CB3



Long-term power stability of CARBIDE-CB3-120W



Model	CB3-20W	CB3-40W	CB3-80W	CB3-120W



OUTPUT CHARACTERISTICS

Cooling method		Water-cooled			
Center wavelength 1)		1030 ± 10 nm			
Maximum output power	20 W	20 W 40 W 80 W 120 V			120 W
Pulse duration 2)		< 250 fs		< 350 fs ³⁾	< 250 fs
Pulse duration tuning range		250 fs – 10 ps		350 fs – 10 ps	250 fs – 10 ps
Maximum pulse energy	0.4	0.4 mJ 0.8 mJ		2 mJ	1 mJ
Repetition rate	Single-shot – 1 MHz	Single-shot – 1 MHz (2 MHz on request) Single-shot		hot – 2 MHz	Single-shot – 1 MHz (2 MHz on request)
Pulse selection	Single	Single-shot, pulse-on-demand, any fundamental repetition rate division			
Dalawinatian		Linear ventical, 1, 1000			

Pulse selection	Single-shot, pulse-on-demand, any fundamental repetition rate division			/ision
Polarization		Linear, vertical; 1 : 1000)	
Beam quality, M ²		< 1.2		
Beam diameter 4)	3.9 ± 0.4 mm	4.2 ± 0.4 mm	5.1 ± 0.7 mm	4.5 ± 0.5 mm
Beam pointing stability		< 20 μrad/°C		
Pulse picker	FEC ⁵⁾			
Pulse picker leakage		< 0.25%		
Pulse-to-pulse energy stability, 24 h 6)		< 0.5%		
Long-term power stability, 100 h ⁶⁾		< 0.5%		

MAIN OPTIONS

Oscillator output 7)	< 0.5 W, 120 – 250 fs, 1030 ± 10 nm, ≈ 65 MHz	
Harmonic generator 8)	515 nm, 343 nm, 257 nm, or 206 nm; see page 23	
Optical parametric amplifier 9)	320 – 10000 nm; see page 30 –	
BiBurst option	Tunable GHz and MHz burst with burst-in-burst capability; see page 17	

PHYSICAL DIMENSIONS

Laser head (L × W × H)	632 × 305 × 174 mm	
Chiller (L × W × H)	585 × 484 × 221 mm	680 × 484 × 307 mm
24 V DC power supply (L × W × H) 10)	280 × 144 × 49 mm	320 × 200 × 75 mm

ENVIRONMENTAL AND UTILITY REQUIREMENTS

Operating temperature		15 – 30 °C			
Relative humidity		< 80% (non-condensing)			
Electrical requirements	Laser	100 V AC, 7 A – 240 V AC, 3A; 50 – 60 Hz 100 V AC, 12 A – 240 V AC		, 5 A; 50 – 60 Hz	
Electrical requirements	Chiller	100 – 230 V AC; 50 – 60 Hz	200 – 230 V AC; 50 – 60 Hz		
Laser	Laser	600 W	1000 W	2000 W	
Rated power	Chiller	1400 W	2000 W		
Dannau aa wanna mti a m	Laser	500 W	900 W	1400 W	
Power consumption	Chiller	1000 W	1300 W	1700 W	

- 1) Precise center wavelength for specific models available upon request.
- ²⁾ Assuming Gaussian pulse shape.
- Pulse duration can be reduced to < 250 fs if pulse peak intensity of > 50 GW/cm² is tolerated by the customer setup.
- 4) FW 1/e², using maximum pulse energy.
- 5) Provides fast energy control; external analog control input available. Response time – next available RA pulse.
- 6) Under stable environmental conditions. Expressed as NRMSD (normalized root mean squared deviation).
- 7) Available simultaneously, requires scientific interface. Contact sales@lightcon.com for details or customized solutions.
- 8) Integrated. For external harmonic generator, refer to HIRO.
- 9) Integrated. For more options and OPAs for -4mJ and -UP models, refer to ORPHEUS series of OPAs.
- ¹⁰⁾ Power supply can be different if optional 2 MHz version is selected.





CARBIDE-CB5 (AIR-COOLED) SPECIFICATIONS

Model	C	B5	CB5-SP
OUTPUT CHARACTERISTICS			
Cooling method		Air-cooled 1)	
Center wavelength 2)		1030 ± 10 nm	
Maximum output power	6 W	5	W
Pulse duration 3)	< 29	90 fs	< 190 fs
Pulse duration tuning range	290 fs	– 20 ps	190 fs – 20 p
Maximum pulse energy	100 μJ	83 μJ	100 μJ
Repetition rate	Single-shot – 1 MHz		
Pulse selection	Single-shot, pulse-on-demand, any fundamental repetition rate division		
Polarization	Linear, vertical; 1 : 1000		
Beam quality, M ²	<1.2		
Beam diameter ⁴⁾		2.1 ± 0.4 mm	
Beam pointing stability		< 20 μrad/°C	
Pulse picker	Included	Included 5)	Included
Pulse picker leakage	< 2 %	< 0.1 %	< 2 %
Pulse-to-pulse energy stability, 24 h ⁶⁾	< 0.5%		
Long-term power stability, 100 h 6)	< 0.5%		

MAIN OPTIONS

Oscillator output	n/a	
Harmonic generator 7)	515 nm, 343 nm, 257 nm, or 206 nm; see page 23	
Optical parametric amplifier 8)	320 – 10000 nm; see page 30	
BiBurst option	n/a	

PHYSICAL DIMENSIONS

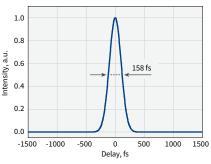
Laser head (L × W × H)	631 × 324 × 162 mm	
Chiller	Not required	
24 V DC power supply (L × W × H)	220 × 95 × 46 mm	

ENVIRONMENTAL AND UTILITY REQUIREMENTS

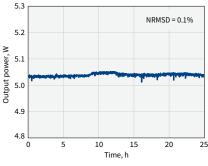
Operating temperature	17 – 27 °C	
Relative humidity	< 80% (non-condensing)	
Electrical requirements	100 V AC, 3 A – 240 V AC, 1.3 A; 50 – 60 Hz	
Rated power	300 W	
Power consumption	150 W	

- 1) Water-cooled version available on request.
- ²⁾ Precise center wavelength for specific models available upon request.
- ³⁾ Assuming Gaussian pulse shape.
- 4) FW 1/e², using maximum pulse energy.
- ⁵⁾ Enhanced contrast AOM. Provides fast amplitude control of output pulse train.
- ⁶⁾ Under stable environmental conditions. Expressed as NRMSD (normalized root mean squared deviation).
- ⁷⁾ Integrated. For external harmonic generator, refer to HIRO.
- 8) Integrated. For stand-alone OPAs, refer to ORPHEUS series of OPAs.

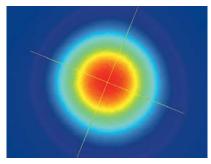




Typical pulse duration of CARBIDE-CB5



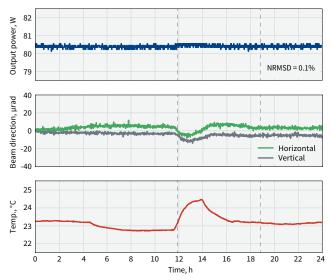
Long-term power stability of CARBIDE-CB5



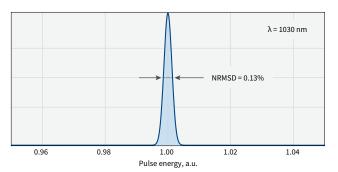
Typical beam profile of CARBIDE-CB5



STABILITY MEASUREMENTS

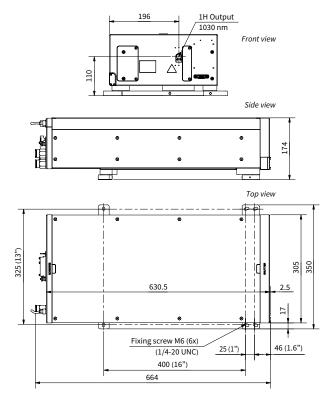


CARBIDE-CB3 output power and beam direction with power lock enabled, under varying environmental conditions

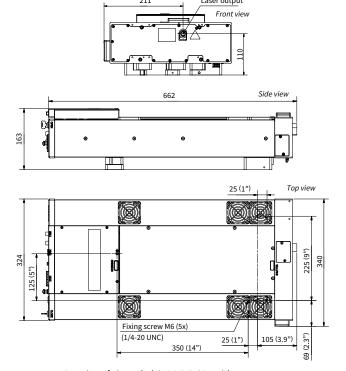


Typical pulse-to-pulse energy stability

DRAWINGS



Drawing of CARBIDE-CB3



Drawing of air-cooled CARBIDE-CB5 with attenuator



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CARBIDE | CB3-UV



High-Power UV Femtosecond Lasers

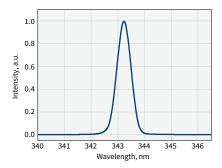
FEATURES

- Maximum output of 50 W
- 500 fs pulse duration
- Up to MHz repetition rate
- High beam quality and stability
- Compact industrial-grade design

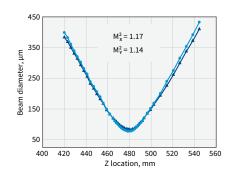


CARBIDE-CB3-UV is a series of femtosecond lasers for high-power ultraviolet (UV) applications. As indicated by its name, the CARBIDE-CB3-UV laser is based on a market-proven industrial-grade CARBIDE laser platform. It emits 500 fs pulses at a 343 nm wavelength and fits into the footprint of 84 × 35 cm², making it the most compact 50 W UV femtosecond laser currently available in the market.

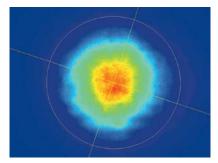
The CARBIDE-CB3-UV ensures long-term performance without the need for user intervention. The high power comes with the advantage of splitting the beam into multiple parts, thereby parallelizing the micromachining processes and subsequently increasing throughput. The CARBIDE platform ensures simple integration into industrial 24/7 workstations.



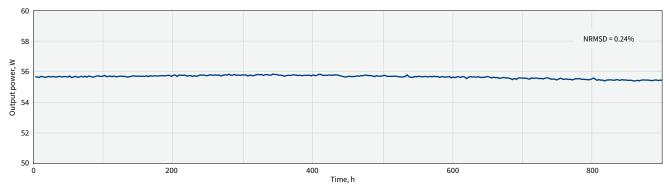
Typical spectrum of CARBIDE-CB3-UV



Typical M² measurement data of CARBIDE-CB3-UV



Beam profile of CARBIDE-CB3-UV-50W



Long-term power stability of CARBIDE-CB3-UV-50W



SPECIFICATIONS

		NEW_	
Model	CB3-UV-30W	CB3-UV-50W	
OUTPUT CHARACTERISTICS			
Cooling method	Water-co	oled	
Center wavelength	343 ± 3	nm	
Maximum output power	> 30 W	> 50 W	
Pulse duration 1)	≈ 500	fs	
Output pulse energy	35 – 150) μJ	
Repetition rate	200 – 800 kHz	300 – 1200 kHz	
Polarization	Linear, vertic	al; 1 : 200	
Beam quality, M ²	< 1.3		
Beam diameter ²⁾	2.5 – 5 mm		
Long-term power stability, 12 h ³⁾	< 0.5%		
Lifetime	10000 h or 1 year		
MAIN OPTIONS			
Optional amplifier outputs	1030 nm, 5	515 nm	
PHYSICAL DIMENSIONS			
Laser head (L × W × H)	832 × 350 ×	174 mm	
Chiller (L × W × H)	680 × 484 × 307 mm		
24 V DC power supply (L × W × H)	320 × 200 × 75 mm		
ENVIRONMENTAL AND UTILITY REQUIREMEN	NTS		
Operating temperature	15 – 30	°C	
The second secon			

< 80% (non-condensing)

100 V AC, 12 A - 240 V AC, 5 A

200 - 230 V AC; 50 - 60 Hz 1000 W

> 2000 W 900 W

1300 W

Laser

Chiller

Laser

Chiller

Laser

Chiller



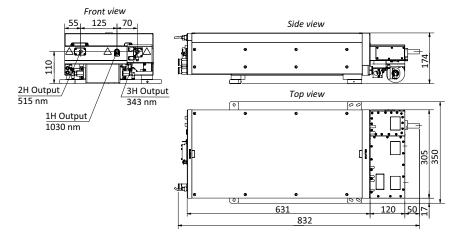
DRAWINGS

Relative humidity

Rated power

Electrical requirements

Power consumption



Drawing of CARBIDE-CB3-UV



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¹⁾ Assuming Gaussian pulse shape.

²⁾ FW 1/e², using maximum pulse energy.

³⁾ Under stable environmental conditions. Expressed as NRMSD (normalized root mean squared deviation).

BiBurst option

Tunable GHz and MHz Burst with Burst-in-Burst Capability

PHAROS and CARBIDE-CB3 lasers have an option for tunable GHz and MHz burst with burst-in-burst capability - called BiBurst.

In standard mode, a single pulse is emitted at some fixed frequency. In burst mode, the output consists of pulse packets instead of single pulses. Each packet consists of a certain number of equally separated pulses. MHz-Burst contains N pulses with a nanosecond period, GHz-Burst contains P pulses with a picosecond period. If both bursts are used, the equally separated pulse packets contain sub-packets of pulses (burst-in-burst, BiBurst).

PHAROS and CARBIDE lasers with the BiBurst option bring new capabilities to high-tech manufacturing industries such as consumer electronics, integrated photonic chip manufacturing, future display manufacturing, and quantum technologies. The applications include:

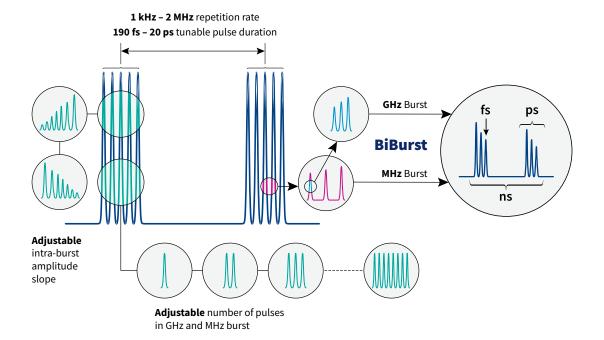
- brittle material drilling and cutting
- deep engraving
- selective ablation
- volume modification of transparent materials
- hidden marking
- surface polishing
- surface functionalization

SPECIFICATIONS

Model		CARBIDE-CB3	PHAROS
CII- Dougt	Intra burst pulse period 1)	440 ± 40 ps	200 ± 40 ps
GHz Burst	Number of pulses, P 2)	1 – 10	1 – 25
MII- Dt	Intra burst pulse period	≈ 15 ns	
MHz Burst	Number of pulses, N	1 – 10	1 – 9 (7 with FEC 3))

¹⁾ Custom spacing is available on request.

³⁾ Fast energy control option. Enables formation of any pulse envelope at laser pulse repetition rate.



²⁾ Maximum number of pulses in a burst depends on the laser repetition rate and the energy. Custom number of pulses is available on request.

HG | CARBIDE

Automated Harmonic Generators

FEATURES

- 515 nm, 343 nm, or 257 nm output
- Automated harmonic selection
- Mounted directly on the laser head
- Industrial-grade design
- 50 W UV model

CARBIDE lasers equipped with automated harmonic generators (HGs) provide a selection of fundamental (1030 nm), second (515 nm), third (343 nm), or fourth (257 nm) harmonic outputs using software control.



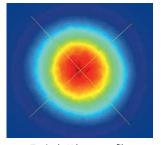
HGs are perfect for industrial applications that require a single-wavelength output. Modules, mounted directly at the output of the laser, are fully integrated into the system.

SPECIFICATIONS

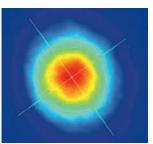
Model		2H	2H-3H	2H-4H	30W UV 1)	50W UV 1)
Output wavelength ²⁾ (automated selection)		1030 nm 515 nm	1030 nm 515 nm 343 nm	1030 nm 515 nm 257 nm	1030 nm 515 nm 343 nm	1030 nm 343 nm
Pump pulse energy		20 – 2000 μJ	50 – 2000 μJ	20 – 2000 μJ	80 – 400 μJ	120 – 400 μJ
Pump pulse duration		< 300 fs			≈ 500 fs	
Conversion efficiency / Output power		> 50% (2H)	> 50% (2H) > 25% (3H)	> 50% (2H) > 10% (4H) ³⁾	40 W (2H) 30 W (3H)	50 W (3H)
Beam quality (M²) typical values	≤ 400 μJ pump	< 1.15 (2H)	< 1.15 (2H) < 1.2 (3H)	< 1.15 (2H) n/a (4H)	< 1.2 (2H) < 1.3 (3H)	< 1.3 (3H)
	> 400 μJ pump	< 1.2 (2H)	< 1.2 (2H) < 1.3 (3H)	< 1.2 (2H) n/a (4H)	n/a	

¹⁾ Refer to CARBIDE-CB3-UV for more details.

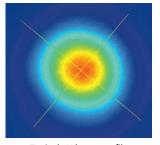




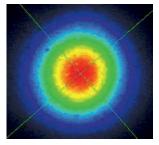
Typical 1H beam profile of CARBIDE-CB5 (100 kHz, 6 W)



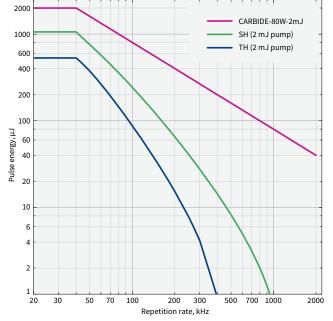
Typical 3H beam profile of CARBIDE-CB5 (100 kHz, 2.2 W)



Typical 2H beam profile of CARBIDE-CB5 (100 kHz, 3.4 W)



Typical 4H beam profile of CARBIDE-CB5 (100 kHz, 100 mW)



Pulse energy vs repetition rate of CARBIDE-CB3-80W with HG

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²⁾ Depends on pump laser model. Up to 5th harmonic available; contact sales@lightcon.com for details.

³⁾ Maximum output power of 2 W.

I-OPA

Industrial-Grade Optical Parametric Amplifier

FEATURES

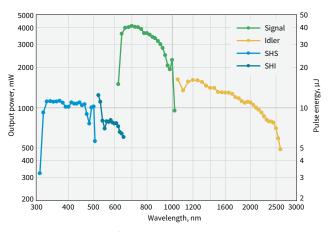
- Wavelength tunability in an industrial design
- Single-box solution
- Tunable or fixed-wavelength models
- Plug-and-play installation and robust performance
- The most compact OPA in the market



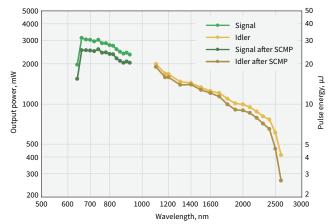
I-OPA-TW on air-cooled CARBIDE-CB5

The industrial-grade optical parametric amplifier I-OPA series marks a new era of simplicity in the world of wavelength-tunable femtosecond sources. Based on decades of experience with optical parametric amplifiers, this solution combines wavelength tunability with robust industrial design. The I-OPA is a rugged module integrated into our PHAROS or CARBIDE lasers, providing stability comparable to that of industrial harmonic generators. The sealed design provides mechanical stability and eliminates the effects of air turbulence, minimizing energy fluctuations and ensuring stable long-term performance.

The tunable I-OPA provides a wide tuning range and is primarily intended for spectroscopy and microscopy applications. In particular, the -HP model is targeted to be coupled with our HARPIA spectroscopy system as a pump beam source for ultrafast pump-probe spectroscopy. The -F model is primarily designed as a light source for multiphoton microscopy, the -ONE model - for IR spectroscopy, and other applications where high-energy MIR pulses are desired. All models can also be used for micromachining and other industrial applications. The fixed-wavelength I-OPA is a costeffective solution when a single wavelength is desired.



Typical I-OPA-TW-HP tuning curves. Pump: 40 W, 400 μJ, 100 kHz



Typical I-OPA-TW-F tuning curves. Pump: 40 W, $400 \mu J$, 100 kHz



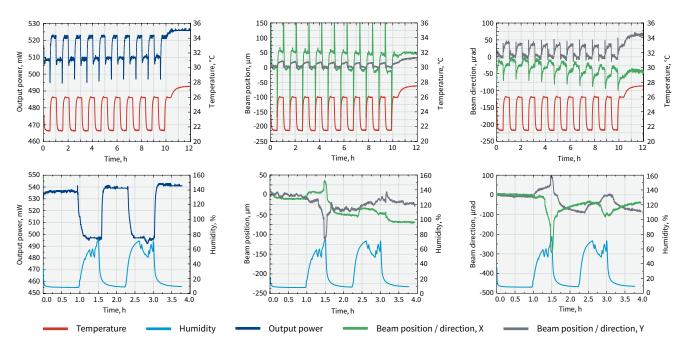
SPECIFICATIONS

Model	I-OPA-HP	I-OPA-F	I-OPA-ONE
Configuration	ORPHEUS	ORPHEUS-F	ORPHEUS-ONE
Pump power			
Pump pulse energy			
Repetition rate			
Tuning range 1)	640 – 1010 nm (Signal) 1050 – 2600 nm (Idler)	650 – 920 nm (Signal) 1200 – 2500 nm (Idler)	1350 – 2000 nm (Signal) 2100 – 4500 nm (Idler)
Communication officiency	> 79 (40 – 400 µJ	> 9% @ 1550 nm (40 – 400 µJ pump; up to 1 MHz)	
Conversion efficiency	> 3.5 (20 – 40 µJ	> 6% @ 1550 nm (20 – 40 μJ pump; up to 2 MHz)	
Spectral bandwidth 2)	80 – 220 cm ⁻¹ @ 700 – 960 nm	200 – 1000 cm ⁻¹ @ 650 – 920 nm 150 – 1000 cm ⁻¹ @ 1200 – 2000 nm	60 – 150 cm ⁻¹ @ 1450 – 2000 nm
Pulse duration ^{2) 3)}	120 – 250 fs	< 55 fs @ 800 – 920 nm < 70 fs @ 650 – 800 nm < 100 fs @ 1200 – 2000 nm	100 – 300 fs
Long-term power stability, 8 h ⁴⁾	< 19	< 1% @ 1550 nm	
Pulse-to-pulse energy stability, 1 min 4)	< 19	< 1% @ 1550 nm	
Wavelength extension options	320 – 505 nm (SHS) ⁵⁾ 525 – 640 nm (SHI) ⁵⁾	Contact sales@lightcon.com	4500 – 10000 nm (DFG) ⁶⁾
Pulse compression options ²⁾	n/a	SCMP (Signal pulse compressor) ICMP (Idler pulse compressor) GDD-CMP (Compressor with GDD control)	n/a

¹⁾ In case of fixed wavelength (FW), a single wavelength can be selected from the Signal or Idler range. Signal may have accessible Idler pair, and vice versa.

 $^{^{6)}}$ Up to 16 μm tuning range is accessible with an external difference frequency generator.





I-OPA output power, beam position, and beam direction under harsh environmental conditions

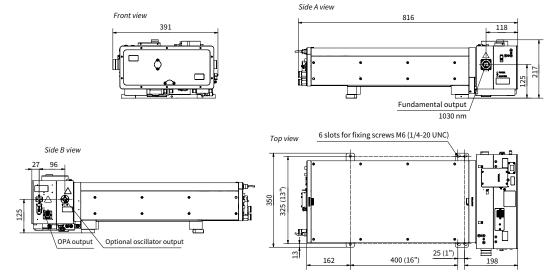
²⁾ I-OPA-F broad-bandwidth pulses are compressed externally. Typical pulse duration before compression: 120 – 250 fs, after compression: 25 – 70 fs @ 650 – 920 nm, 40 – 100 fs @ 1200 – 2000 nm.

³⁾ Output pulse duration depends on the selected wavelength and pump laser pulse duration.

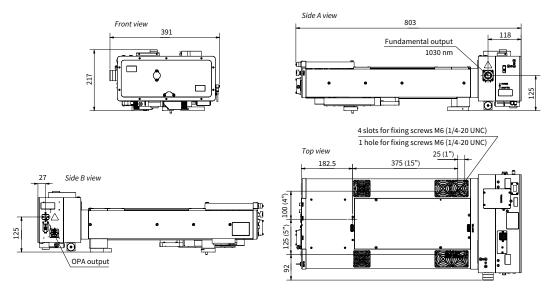
 $^{^{} ext{\tiny 4})}$ Expressed as NRMSD (normalized root mean squared deviation).

⁵⁾ Conversion efficiency is 1.2% at peak; specified as the percentage of pump power.

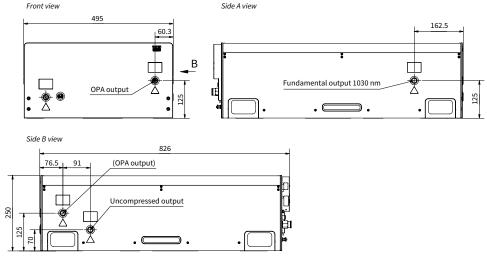
DRAWINGS



Drawing and output ports of CARBIDE-CB3 with wavelength-tunable/fixed I-OPA-HP



Drawing and output ports of CARBIDE-CB5 with wavelength-tunable/fixed I-OPA-HP



Drawing and output ports of PHAROS-PH2 with wavelength-tunable/fixed I-OPA-HP

